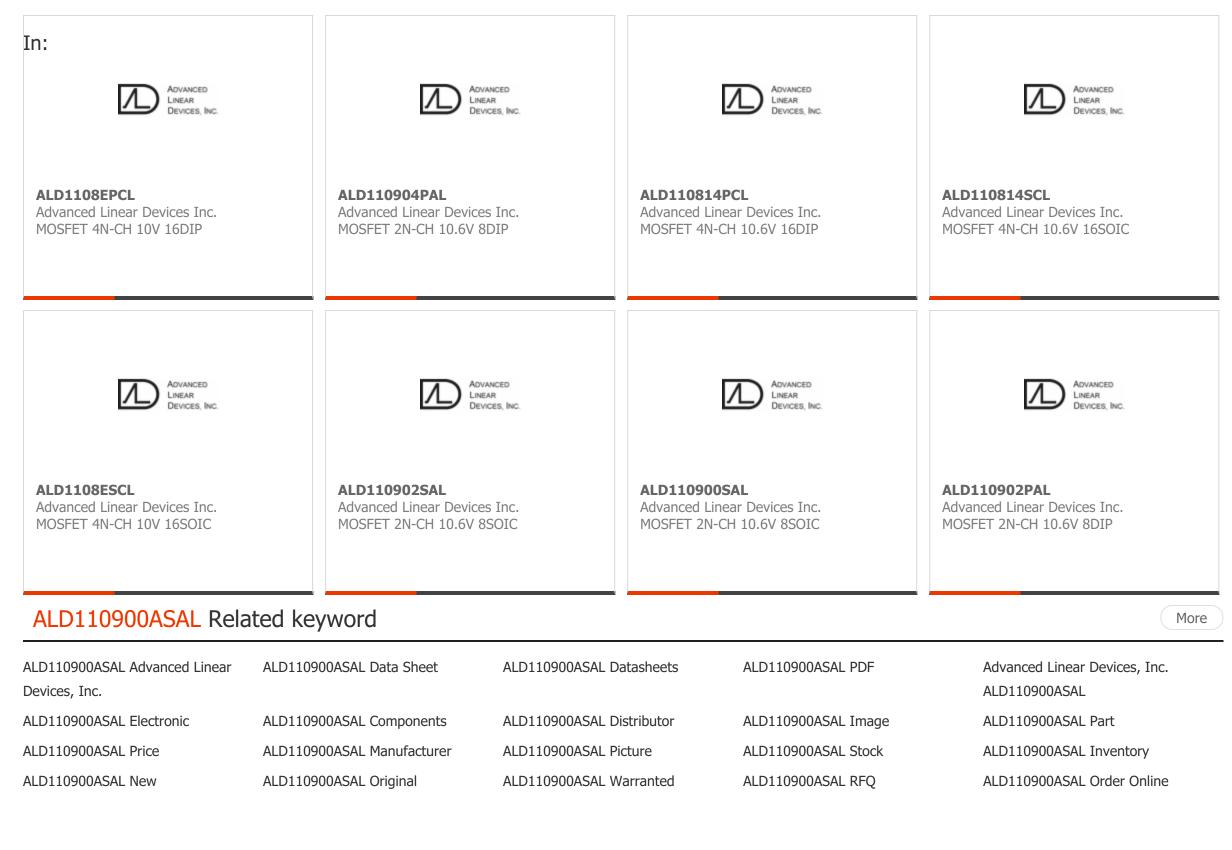


Specifications

Part Number	ALD110900ASAL
Manufacturer	Advanced Linear Devices, Inc.
Description	MOSFET 2N-CH 10.6V 8SOIC
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2565 pcs Stock
Vgs(th) (Max) @ Id	10mV @ 1µA
Supplier Device Package	8-SOIC
Series	EPAD®, Zero Threshold™
Rds On (Max) @ Id, Vgs	500 Ohm @ 4V
Power - Max	500mW
Packaging	Tube
Package / Case	8-SOIC (0.154", 3.90mm Width)
Operating Temperature	0°C ~ 70°C (TJ)
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	2.5pF @ 5V
Gate Charge (Qg) (Max) @ Vgs	-
FET Туре	2 N-Channel (Dual) Matched Pair
FET Feature	Standard
Drain to Source Voltage (Vdss)	10.6V
Current - Continuous Drain (Id) @ 25°C	-

You May Be Also Be interested



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